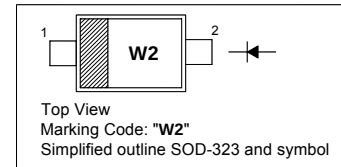


BAS216WS

High Speed Switching Diode

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

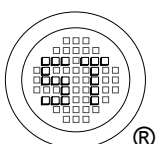


Absolute Maximum Ratings ($T_a = 25\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	85	V
Reverse Voltage	V_R	75	V
Continuous Forward Current	I_F	250	mA
Repetitive Peak Forward Current	I_{FRM}	500	mA
Non-Repetitive Peak Forward Current	I_{FSM}	4 1 0.5	A
		$t = 1\text{ }\mu\text{s}$ $t = 1\text{ ms}$ $t = 1\text{ s}$	
Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^{\circ}\text{C}$

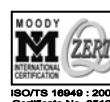
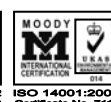
Characteristics at $T_a = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 1\text{ mA}$ at $I_F = 10\text{ mA}$ at $I_F = 50\text{ mA}$ at $I_F = 150\text{ mA}$	V_F	0.715 0.855 1 1.25	V
Reverse Current at $V_R = 25\text{ V}$ at $V_R = 75\text{ V}$ at $V_R = 25\text{ V}$, $T_J = 150\text{ }^{\circ}\text{C}$ at $V_R = 75\text{ V}$, $T_J = 150\text{ }^{\circ}\text{C}$	I_R	30 1 30 50	nA μA μA μA
Diode Capacitance at $V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_{tot}	1.5	pF
Reverse Recovery Time at $I_F = 10\text{ mA}$ to $I_R = 10\text{ mA}$, $I_R = 1\text{ mA}$, $R_L = 100\text{ }\Omega$	t_{rr}	4	ns

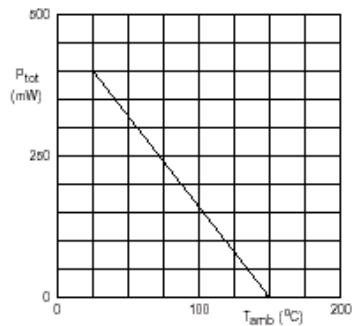


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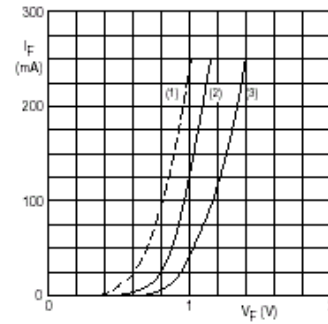


Dated : 07/04/2009



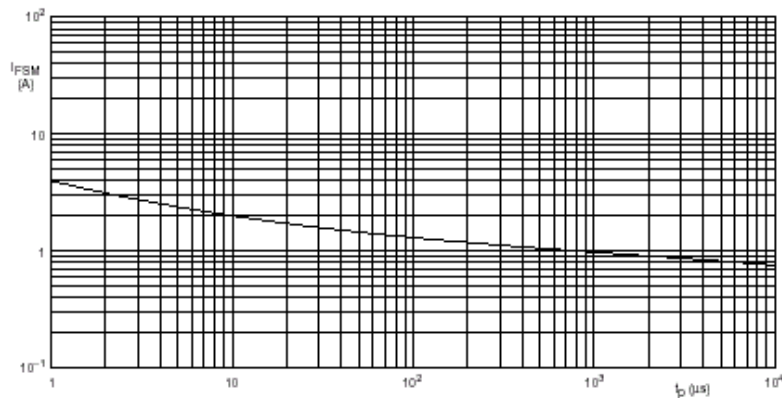
Device mounted on an FR4 printed-circuit board.

Maximum permissible total power dissipation as a function of ambient temperature.



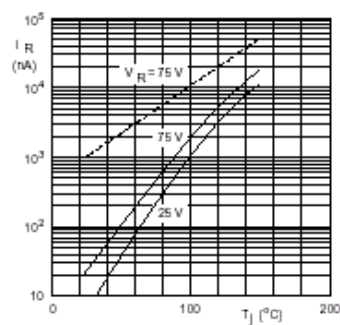
- (1) $T_j = 150\text{ }^{\circ}\text{C}$; typical values.
- (2) $T_j = 25\text{ }^{\circ}\text{C}$; typical values.
- (3) $T_j = 25\text{ }^{\circ}\text{C}$; maximum values.

Forward current as a function of forward voltage.



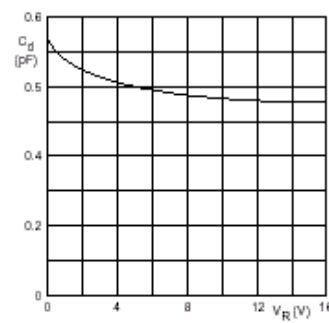
Based on square wave currents.
 $T_j = 25\text{ }^{\circ}\text{C}$ prior to surge.

Maximum permissible non-repetitive peak forward current as a function of pulse duration.



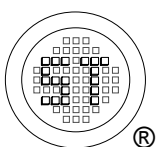
Dotted line: maximum values.
Solid line: typical values.

Reverse current as a function of junction temperature.

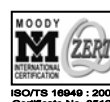
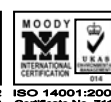
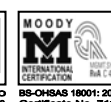


$f = 1\text{ MHz}$; $T_j = 25\text{ }^{\circ}\text{C}$.

Diode capacitance as a function of reverse voltage; typical values.



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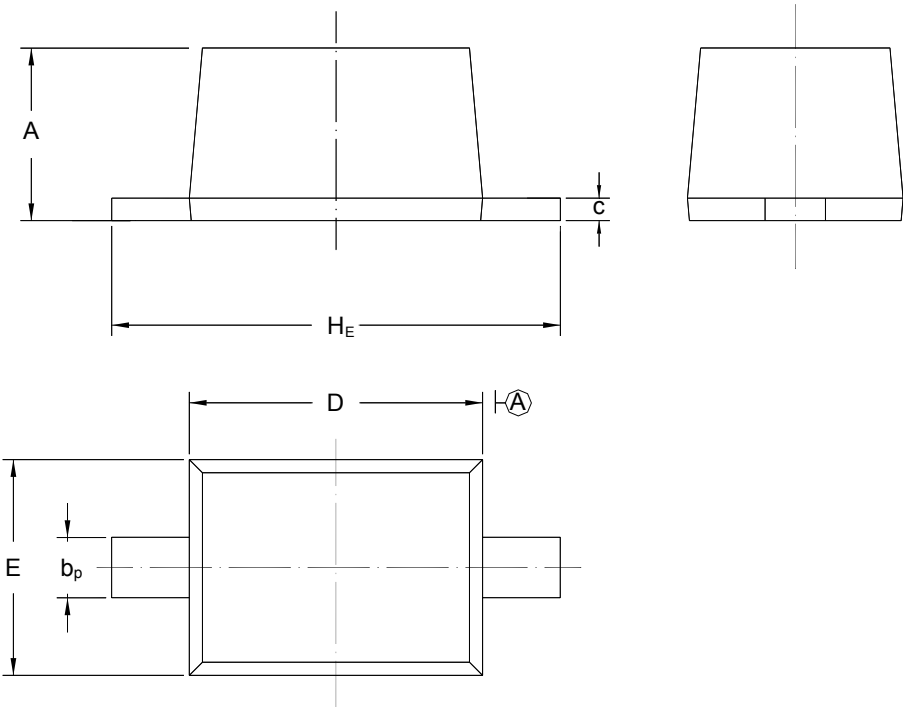


Dated : 07/04/2009

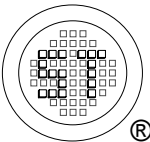
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	b _p	C	D	E	H _E
mm	1.10 0.80	0.40 0.25	0.15 0.00	1.80 1.60	1.35 1.15	2.80 2.30



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